



SLLS666-SEPTEMBER 2005

# HIGH OUTPUT FULL-DUPLEX RS-485 DRIVERS AND RECEIVERS

## FEATURES

- 1/8 Unit-Load Option Available (Up to 256 Nodes on the Bus)
- Bus-Pin ESD Protection Exceeds 15 kV HBM
- Optional Driver Output Transition Times for Signaling Rates <sup>(1)</sup> of 1 Mbps, 5 Mbps and 25 Mbps
- Low-Current Standby Mode < 1 μA</li>
- Glitch-Free Power-Up and Power-Down Bus
  I/Os
- Bus Idle, Open, and Short Circuit Failsafe
- Meets or exceeds the requirements of ANSI TIA/EIA-485-A and RS-422 Compatible
- 3.3-V Devices available, SN65HVD30-39

## **APPLICATIONS**

- Utility Meters
- Chassis-to-Chassis Interconnects
- DTE/DCE Interfaces
- Industrial, Process, and Building Automation
- Point-of-Sale (POS) Terminals and Networks

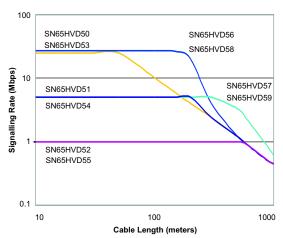
## DESCRIPTION

The SN65HVD5X devices are 3-state differential line drivers and differential-input line receivers that operate with a 5-V power supply. Each driver and receiver has separate input and output pins for full-duplex bus communication designs. They are designed for balanced transmission lines and interoperation with ANSI TIA/EIA-485A, TIA/EIA-422-B, ITU-T v.11 and ISO 8482:1993 standard-compliant devices.

 The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second). The SN65HVD50, SN65HVD51, SN65HVD52, SN65HVD56 and SN65HVD57 are fully enabled with no external enabling pins. The SN65HVD56 and SN65HVD57 implement receiver equalization technology for improved performance in long distance applications.

The SN65HVD53, SN65HVD54, SN65HVD55, SN65HVD58, and SN65HVD59 have active-high driver enables and active-low receiver enables. A very low, less than 1 uA, standby current can be achieved by disabling both the driver and receiver. The SN65HVD58 and SN65HVD59 implement receiver equalization technology for improved performance in long distance applications.

All devices are characterized for operation from -40° C to +85°.



The SN65HVD56 and SN65HVD58 implement receiver equalization technology for improved jitter performance on differential bus applications with data rates up to 20 Mbps at cable lengths up to 160 meters.

The SN65HVD57 and SN65HVD59 implement receiver equalization technology for improved jitter performance on differential bus applications with data rates in the range of 1 to 5 Mbps at cable lengths up to 1000 meters.



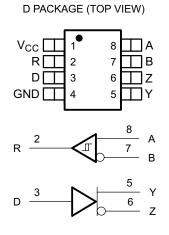
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SLLS666-SEPTEMBER 2005

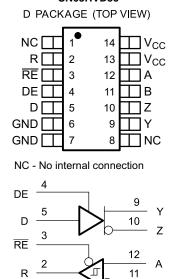


These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### SN65HVD50, SN65HVD51, SN65HVD52, SN65HVD56, SN65HVD57



SN65HVD53, SN65HVD54, SN65HVD55, SN65HVD58, SN65HVD59



в

#### **AVAILABLE OPTIONS**

SIGNALING RATE	UNIT LOADS	RECEIVER EQUALIZATION	ENABLES	BASE PART NUMBER	SOIC MARKING
25 Mbps	1/2	No	No	SN65HVD50	PREVIEW
5 Mbps	1/8	No	No	SN65HVD51	PREVIEW
1 Mbps	1/8	No	No	SN65HVD52	PREVIEW
25 Mbps	1/2	No	Yes	SN65HVD53	65HVD53
5 Mbps	1/8	No	Yes	SN65HVD54	65HVD54
1 Mbps	1/8	No	Yes	SN65HVD55	65HVD55
25 Mbps	1/2	Yes	No	SN65HVD56	PREVIEW
5 Mbps	1/8	Yes	No	SN65HVD57	PREVIEW
25 Mbps	1/2	Yes	Yes	SN65HVD58	PREVIEW
5 Mbps	1/8	Yes	Yes	SN65HVD59	PREVIEW

## **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted)<sup>(1)(2)</sup>

		UNIT
V <sub>CC</sub>	Supply voltage range	–0.3 V to 6 V
	Voltage range at any bus terminal (A, B, Y, Z)	–9 V to 14 V
	Voltage input, transient pulse through 100 $\Omega$ . See Figure 12 (A, B, Y, Z) <sup>(3)</sup>	–50 to 50 V
VI	Voltage input range (D, DE, RE)	-0.5 V to 7 V
	Continuous total power dissipation	Internally limited
I <sub>O</sub>	Output current (receiver output only, R)	11 mA

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

(3) This tests survivability only and the output state of the receiver is not specified.

### **RECOMMENDED OPERATING CONDITIONS**

over operating free-air temperature range (unless otherwise noted)

PARA	METER			MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage	Supply voltage				5.5	
V <sub>I</sub> or V <sub>IC</sub>	Voltage at any bus terr	Voltage at any bus terminal (separately or common mode)				12	V
1/t <sub>UI</sub>		SN65HVD50, SN65HVD53, SN65H	IVD56, SN65HVD58			25	
	Signaling rate	SN65HVD51, SN65HVD54, SN65H	IVD57, SN65HVD59			5	Mbps
		SN65HVD52, SN65HVD55				1	
RL	Differential load resista	esistance		54	60		Ω
VIH	High-level input voltage	9	D, DE, RE	2		$V_{CC}$	
VIL	Low-level input voltage	•	D, DE, RE	0		0.8	V
V <sub>ID</sub>	Differential input voltage	le		-12		12	
		-1	Driver	-60			0
I <sub>OH</sub>	High-level output curre	nt	Receiver	-8			mA
	Low-level output current		Driver			60	
I <sub>OL</sub>			Receiver			8	mA
T <sub>J</sub> <sup>(2)</sup>	Junction temperature			-40		150	°C

(1) The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

(2) See thermal characteristics table for information regarding this specification.

## ELECTROSTATIC DISCHARGE PROTECTION

PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
Human body model	Bus terminals and GND		±16		
Human body model <sup>(2)</sup>	All pins		<u>+</u> 4		kV
Charged-device-model <sup>(3)</sup>	All pins		±1		

(1) All typical values at 25°C and with a 5-V supply.

(2) Tested in accordance with JEDEC Standard 22, Test Method A114-A.

(3) Tested in accordance with JEDEC Standard 22, Test Method C101.

TEXAS INSTRUMENTS www.ti.com

SLLS666-SEPTEMBER 2005

### **DRIVER ELECTRICAL CHARACTERISTICS**

over recommended operating conditions unless otherwise noted

	PARAMETER		TEST CON	IDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
V <sub>I(K)</sub>	Input clamp voltage		I <sub>I</sub> = -18 mA		-1.5			
			I <sub>O</sub> = 0		4		V <sub>CC</sub>	
N7 1	Ota a du atata diffanantia		$R_L = 54 \Omega$ , See Fig	ure 1 (RS-485)	1.7	2.6		
V <sub>OD(SS)</sub>	Steady-state differentia	ii output voitage	$R_L = 100 \Omega$ , See Fi	gure 1 (RS-422)	2.4	3.2		
			$V_{\text{test}} = -7$ V to 12 V	, See Figure 2	1.6			
$\Delta  V_{OD(SS)} $	Change in magnitude o differential output volta		$R_L = 54 \Omega$ , See Fig Figure 2	ure 1 and	-0.2		0.2	
V <sub>OD(RING)</sub>	Differential Output Volt and undershoot	age overshoot	$R_L = 54 \Omega, C_L = 50$ Figure 5 See Figure 3 for de				0.05  V <sub>OD(SS)</sub>	V
	Peak-to-peak	HVD50, HVD53, HVD56, HVD58				0.5		
V <sub>OC(PP)</sub>	common-mode output voltage	HVD51, HVD54, HVD57, HVD59	See Figure 4			0.4		
		HVD52, HVD55				0.4		
V <sub>OC(SS)</sub>	Steady-state common- output voltage	mode			2.2		3.3	
$\Delta V_{OC(SS)}$	Change in steady-state output voltage	common-mode	- See Figure 4		-0.1		0.1	
			$V_{CC} = 0 V, V_Z \text{ or } V_V$ Other input at 0 V	<sub>Y</sub> = 12 V,			90	
			$V_{CC} = 0 V, V_Z \text{ or } V_V$ Other input at 0 V	$_{\rm Y} = -7 \ {\rm V},$	-10			
$I_{Z(Z)} \text{ or } I_{Y(Z)}$	High-impedance state output current	HVD53, HVD54,	$V_{CC} = 5 V \text{ or } 0 V,$ DE = 0 V $V_Z \text{ or } V_Y = 12 V$	Other input			90	μA
		HVD55, HVD58, HVD59	$V_{CC} = 5 V \text{ or } 0 V,$ DE = 0 V $V_Z \text{ or } V_Y = -7 V$	at 0 V	-10			
1	Oh ant Oinsuit autration		$V_Z$ or $V_Y$ = -7 V	Other input	-250		250	
$I_{Z(S)}$ or $I_{Y(S)}$	Short Circuit output Cu	rrent	$V_Z$ or $V_Y$ = 12 V	at 0 V	-250		250	mA
l <sub>l</sub>	Input current	D, DE			0		100	μA
C <sub>(OD)</sub>	Differential output capa	icitance	V <sub>OD</sub> = 0.4 sin (4E6) DE at 0 V	πt) + 0.5 V,		16		pF

(1) All typical values are at  $25^{\circ}$ C and with a 5-V supply.

### **DRIVER SWITCHING CHARACTERISTICS**

over recommended operating conditions unless otherwise noted

	PARAM	ETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT	
		HVD50, HVD53, HVD56, HVD58		4	8	12		
t <sub>PLH</sub>	Propagation delay time, low-to-high-level output	HVD51, HVD54, HVD57, HVD59		20	29	46	ns	
		HVD52, HVD55		90	143	230		
		HVD50, HVD53, HVD56, HVD58		4	8	12		
t <sub>PHL</sub>	Propagation delay time, high-to-low-level output	HVD51, HVD54, HVD57, HVD59		20	30	46	ns	
		HVD52, HVD55		90	143	230		
		HVD50, HVD53, HVD56, HVD58		3	6	12		
t <sub>r</sub>	Differential output signal rise time	HVD51, HVD54, HVD57, HVD59		25	34	60	ns	
		HVD52, HVD55	$R_{L} = 54 \Omega, C_{L} = 50 \text{ pF},$	130	197	300		
		HVD50, HVD53, HVD56, HVD58	See Figure 5	3	6	11	ns	
t <sub>f</sub>	Differential output signal fall time	HVD51, HVD54, HVD57, HVD59		25	33	60		
		HVD52, HVD55		130	192	300		
		HVD50, HVD53, HVD56, HVD58				2	2	
t <sub>sk(p)</sub>	Pulse skew ( t <sub>PHL</sub> - t <sub>PLH</sub>  )	HVD51, HVD54, HVD57, HVD59				2	ns	
		HVD52, HVD55				8		
	Part-to-part skew	HVD50, HVD53, HVD56, HVD58			1			
t <sub>sk(pp)</sub> <sup>(2)</sup>		HVD51, HVD54, HVD57, HVD59			4			
		HVD52, HVD55			22			
	Propagation delay time,	HVD53, HVD58				30		
t <sub>PZH1</sub>	high-impedance-to-high-	HVD54, HVD59	R <sub>L</sub> = 110 Ω, <u>RE</u> at 0 V,			180	ns	
	level output	HVD55	See Figure 6			380		
	Propagation delay time,	HVD53, HVD58	D = 3 V and $S1 = Y$ ,			16		
t <sub>PHZ</sub>	high-level-to-high-	HVD54, HVD59	- D = 0 V and S1 = Z			40	) ns	
	impedance output	HVD55				110		
	Propagation delay time,	HVD53, HVD58				23		
t <sub>PZL1</sub>	high-impedance-to-low-level	HVD54, HVD59	$P = 110.0$ $\overline{PE}$ at 0.1/			200	ns	
	output	HVD55	- R <sub>L</sub> = 110 Ω, RE at 0 V, See Figure 7			420		
	Propagation delay time,	HVD53, HVD58	D = 3 V and $S1 = Z$ ,			19		
t <sub>PLZ</sub>	low-level-to-high-impedance	HVD54, HVD59	- D = 0 V and S1 = Y			70	ns	
	output	HVD55				160		
t <sub>PZH2</sub>	Propagation delay time, stan				3300	ns		
t <sub>PZL2</sub>	Propagation delay time, stand	$ \begin{array}{l} R_{L} = 110 \; \Omega, \; \overline{RE} \; \mathrm{at} \; 3 \; V, \\ See \; \overline{Figure} \; 7 \\ D = 3 \; V \; \mathrm{and} \; S1 = Z, \\ D = 0 \; V \; \mathrm{and} \; S1 = Y \end{array} $			3300	ns		

All typical values are at 25°C and with a 5-V supply.
 t<sub>sk(pp)</sub> is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

## **RECEIVER ELECTRICAL CHARACTERISTICS**

over recommended operating conditions unless otherwise noted

	PARAMETER	R	TEST CONDITIO	TEST CONDITIONS		TYP <sup>(1)</sup>	MAX	UNIT
V <sub>IT+</sub>	Positive-going diffe threshold voltage	rential input	$I_0 = -8 \text{ mA}$				-0.02	
V <sub>IT-</sub>	Negative-going diff threshold voltage	erential input	I <sub>O</sub> = 8 mA		-0.20			V
V <sub>hys</sub>	Hysteresis voltage	(V <sub>IT+</sub> - V <sub>IT-</sub> )				50		mV
V <sub>IK</sub>	Enable-input clamp	voltage	$I_{I} = -18 \text{ mA}$		-1.5			V
	0 4 4 4		V <sub>ID</sub> = 200 mV, I <sub>O</sub> = -8 mA, Se	e Figure 8	4.0			.,
Vo	Output voltage		$V_{ID} = -200 \text{ mV}, I_O = 8 \text{ mA}, \text{See Figure 8}$				0.3	V
I <sub>O(Z)</sub>	High-impedance-st current	ate output	$V_0 = 0 \text{ or } V_{CC} \overline{RE} \text{ at } V_{CC}$		-1		1	μΑ
			$V_A$ or $V_B = 12 V$	$V_{\rm A}$ or $V_{\rm B}$ = 12 V		0.19	0.3	
		HVD50, HVD53,	$V_A$ or $V_B = 12$ V, $V_{CC} = 0$ V	Other input		0.24	0.4	
		HVD56,	$V_A \text{ or } V_B = -7 \text{ V}$	at 0 V	-0.35	-0.19		mA
		HVD58	$V_A \text{ or } V_B = -7 \text{ V}, V_{CC} = 0 \text{ V}$		-0.25	-0.14		
$I_A \text{ or } I_B$	Bus input current	HVD51,	$V_A \text{ or } V_B = 12 \text{ V}$			0.05	0.10	
		HVD52,	$V_A \text{ or } V_B = 12 \text{ V}, \text{ V}_{CC} = 0 \text{ V}$	Otheringut		0.06	0.10	
		HVD54, HVD55,	$V_A \text{ or } V_B = -7 \text{ V}$	Other input at 0 V	-0.10	-0.05		mA
		HVD57, HVD59	$V_A \text{ or } V_B = -7 \text{ V}, V_{CC} = 0 \text{ V}$		-0.10	-0.03		
		HVD59	V <sub>IH</sub> = 2 V		-60			μA
I <sub>IH</sub>	Input current, RE		$V_{IL} = 0.8 V$		-60			μΑ
CID	Differential input ca	nacitance	$V_{IL} = 0.8 V$ $V_{ID} = 0.4 \sin (4E6\pi t) + 0.5 V, DE at 0 V$		00	16		pF
	HVD50, HVD51, HVD52 HVD56,		_ D at 0 V or V <sub>CC</sub> and No Load				8.0	
		HVD57						m۵
		HVD53		-			2.3	mA
		HVD54, HVD55	RE at 0 V, D at 0 V or V <sub>CC</sub> , D No load (Receiver enabled an			2.9		
		HVD58, HVD59	driver disabled)				4.5	
I <sub>CC</sub>	Supply current	HVD53, HVD54, HVD55, HVD58, HVD59	$\overline{\text{RE}}$ at V <sub>CC</sub> , D at V <sub>CC</sub> , DE at 0 No load (Receiver disabled ar driver disabled)	V, nd		0.08	1	μΑ
		HVD53					2.7	
		HVD54, HVD55	RE at 0 V, D at 0 V or V <sub>CC</sub> , D No load (Receiver enabled an				8.0	
		HVD58	driver enabled)				4.3	
		HVD59					9.7	
		HVD53					2.3	mA
		HVD54, HVD55	RE at V <sub>CC</sub> , D at 0 V or V <sub>CC</sub> , D No load (Receiver disabled ar	PE at V <sub>CC</sub>			7.7	
		HVD58	No load (Receiver disabled and driver enabled)				3.2	
		HVD59	-	-			8.5	

TEXAS INSTRUMENTS www.ti.com

(1) All typical values are at 25°C and with a 5-V supply.

### **RECEIVER SWITCHING CHARACTERISTICS**

over recommended operating conditions unless otherwise noted

	PARAM	ETER	TEST CONDITIONS	MIN TYP <sup>(1)</sup>	MAX	UNIT
	Propagation delay time,	HVD50, HVD53, HVD56, HVD58		24	40	
t <sub>PLH</sub>	low-to-high-level output	HVD51, HVD52, HVD54, HVD55, HVD57, HVD59		43	55	
	Propagation delay time,	HVD50, HVD53, HVD56, HVD58		26	35	
t <sub>PHL</sub>	high-to-low-level output	HVD51, HVD52, HVD54, HVD55, HVD57, HVD59		47	60	
t <sub>sk(p)</sub>	Pulse skew ( t <sub>PHL</sub> - t <sub>PLH</sub>  )	HVD50, HVD53, HVD56, HVD57, HVD58, HVD59	$V_{ID} = -1.5 V \text{ to } 1.5 V,$ $C_L = 15 \text{ pF},$		5	
on(p)		HVD51, HVD54, HVD52, HVD55	See Figure 9		7	ns
		HVD50, HVD53, HVD56, HVD58		5		
t <sub>sk(pp)</sub> <sup>(2)</sup>	Part-to-part skew	HVD51, HVD54, HVD57, HVD59		6		
		HVD52, HVD55		6		
t <sub>r</sub>	Output signal rise time			2.3	4	
t <sub>f</sub>	Output signal fall time			2.4	4	
t <sub>PHZ</sub>	Output disable time from high	level	DE at 3 V, C <sub>I</sub> = 15 pF		17	
t <sub>PZH1</sub>	Output enable time to high leve	vel	See Figure 10		10	
t <sub>PZH2</sub>	Propagation delay time, standby-to-high-level output		DE at 0 V, C <sub>L</sub> = 15 pF See Figure 10		3300	
t <sub>PLZ</sub>	Output disable time from low level		DE at 3 V, $C_L = 15 \text{ pF}$		13	
t <sub>PZL1</sub>	Output enable time to low leve	el	See Figure 11	10		
t <sub>PZL2</sub>	Propagation delay time, stand	by-to-low-level output	DE at 0 V, C <sub>L</sub> = 15 pF See Figure 11		3300	

(1)

All typical values are at 25°C and with a 5-V supply  $.t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits. (2)



#### **RECEIVER EQUALIZATION CHARACTERISTICS**

over recommended operating conditions unless otherwise noted<sup>(1)</sup>

I	PARAMETER		TEST COND	ITIONS		MIN	TYP <sup>(2)</sup>	MAX	UNIT										
				0 m	HVD56, HVD58		PREVIEW		ns										
				100 m	HVD53		PREVIEW												
				100 m	HVD56, HVD58		PREVIEW												
			25 Mbps	150 m	HVD53		PREVIEW												
				150 11	HVD56, HVD58		PREVIEW												
				200 m	HVD53		PREVIEW												
				200 m	HVD56, HVD58		PREVIEW												
				200 m	HVD53		PREVIEW												
	Peak-to-peak			200 m	HVD56, HVD58		PREVIEW												
		Pseudo-random NRZ code with a bit pattern length o 216-1, Belden	10 Mbps	10 Mbps	250 m	HVD53		PREVIEW											
t <sub>j(pp)</sub>	eye-pattern				ro wips										TO Mups		250 11	HVD56, HVD58	
	jitter	3105A cable		300 m	HVD53		PREVIEW												
				300 m	HVD56, HVD58		PREVIEW												
			5 Mbpp	500 m	HVD54		PREVIEW												
			5 Mbps	500 m	HVD57, HVD59		PREVIEW												
					HVD53		PREVIEW												
			2 Mhaa	500	HVD54		PREVIEW												
		3 Mbps	3 Mops	500 m	HVD56, HVD58		PREVIEW												
					HVD57, HVD59		PREVIEW												
					4. 1.46	4. 1.41	4. 1.41	4 Million	1000 m	HVD54		PREVIEW							
			1 Mbps	1000 m	HVD57, HVD59		PREVIEW		1										

(1) The HVD53 and HVD54 do not have receiver equalization but are specified for comparison. (2) All typical values are at  $V_{CC} = 5 V$ , and temperature = 25°C.

## THERMAL CHARACTERISTICS

over operating free-air temperature range unless otherwise noted<sup>(1)</sup>

	PARAMETER	TEST CONDITIONS		MIN TY	P MAX	UNIT	
	Junction-to-ambient	Low-K board <sup>(3)</sup> , No airflow	HVD50, HVD51, HVD52, HVD56, HVD57	230	.8		
0	thermal resistance <sup>(2)</sup>		HVD53, HVD54, HVD55, HVD58, HVD59	162	.6		
$\theta_{JA}$	Junction-to-ambient	High-K board <sup>(4)</sup> , No airflow	HVD50, HVD51, HVD52, HVD56, HVD57	135	.1		
	thermal resistance <sup>(2)</sup>	rmal resistance <sup>(2)</sup>	HVD53, HVD54, HVD55, HVD58, HVD59	92	.1	°C/W	
0	Junction-to-board	High-K board	HVD50, HVD51, HVD52, HVD56, HVD57	44	.4	-C/vv	
$\theta_{JB}$	thermal resistance		HVD53, HVD54, HVD55, HVD58, HVD59	61	.1		
0	Junction-to-case thermal resistance	No board	HVD50, HVD51, HVD52, HVD56, HVD57	43	.5		
$\theta_{\text{JC}}$		NO DOATO	HVD53, HVD54, HVD55, HVD58, HVD59	58	.6		
		evice power signaling rate $R_L = 60\Omega, C_L = 50 \text{ pF}, DE at V = BE at V = BE at 0 V$	HVD50, HVD56 (25Mbps)		420		
			HVD51, HVD57 (10Mbps)		404		
	Deriver		HVD52 (1Mbps)		383		
$P_D$	dissipation		HVD53, HVD58 (25Mbps)		420	mW	
			HVD54, HVD59 (10Mbps)		404		
		square wave at indicated signaling rate	HVD55 (1Mbps)		383		
		Low-K board, No airflow	HVD50, HVD56	-40	55		
			HVD51, HVD52, HVD57	-40	84		
T <sub>A</sub>	Ambient air temperature		HVD53, HVD54, HVD55, HVD58, HVD59	-40	85	°C	
		High-K board, No airflow	HVD50, HVD51, HVD52, HVD56, HVD57	-40	85		
			HVD53, HVD54, HVD55, HVD58, HVD59	-40	85		
T <sub>JSD</sub>	Thermal shutdown jur	nction temperature		16	5		

(1) See Application Information section for an explanation of these parameters.

(2) The intent of  $\theta_{JA}$  specification is solely for a thermal performance comparison of one package to another in a standardized environment. This methodology is not meant to and will not predict the performance of a package in an application-specific environment.

(3) In accordance with the Low-K thermal metric definitions of EIA/JESD51-3.
 (4) In accordance with the High-K thermal metric definitions of EIA/JESD51-7.

## PARAMETER MEASUREMENT INFORMATION

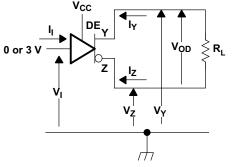


Figure 1. Driver V<sub>OD</sub> Test Circuit: Voltage and Current Definitions

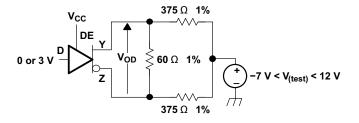


Figure 2. Driver V<sub>OD</sub> With Common-Mode Loading Test Circuit

SLLS666-SEPTEMBER 2005

### PARAMETER MEASUREMENT INFORMATION (continued)

VOD(RING) is measured at four points on the output waveform, corresponding to overshoot and undershoot from the VOD(H) and VOD(L) steady state values.

TEXAS STRUMENTS www.ti.com

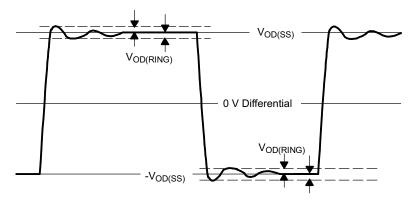
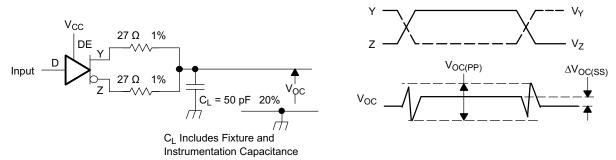
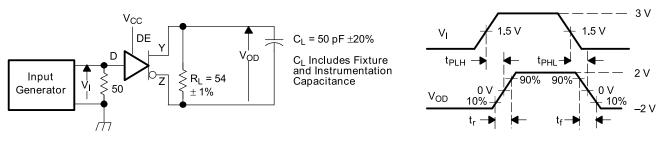


Figure 3. V<sub>OD(RING)</sub> Waveform and Definitions



Input: PRR = 500 kHz, 50% Duty Cycle,t r<6ns, tf<6ns, Z<sub>O</sub> = 50  $\Omega$ 

#### Figure 4. Test Circuit and Definitions for the Driver Common-Mode Output Voltage

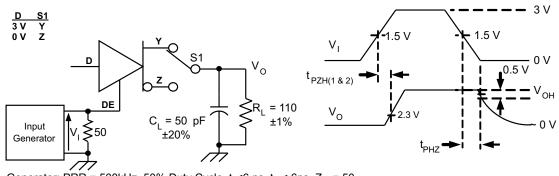


Generator: PRR = 500 kHz, 50% Duty Cycle,  $t_r < 6 \text{ ns}$ ,  $t_f < 6 \text{ ns}$ ,  $Z_0 = 50$ 

#### Figure 5. Driver Switching Test Circuit and Voltage Waveforms

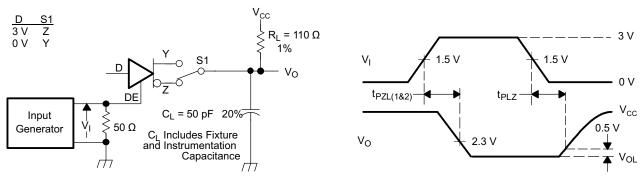
SLLS666-SEPTEMBER 2005

### PARAMETER MEASUREMENT INFORMATION (continued)



Generator: PRR = 500kHz, 50% Duty Cycle,  $t_r < 6 \text{ ns}$ ,  $t_f < 6 \text{ ns}$ ,  $Z_0 = 50$ C<sub>1</sub> Includes Fixture and Instrumentation Capacitance

#### Figure 6. Driver High-Level Output Enable and Disable Time Test Circuit and Voltage Waveforms



Generator: PRR = 500 kHz, 50% Duty Cycle, t  $_r$  <6 ns, t $_f$  <6 ns, Z $_o$  = 50  $\Omega$ 

#### Figure 7. Driver Low-Level Output Enable and Disable Time Test Circuit and Voltage Waveforms

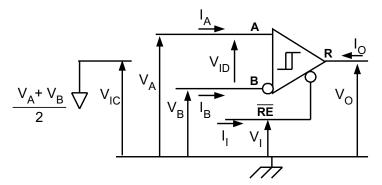
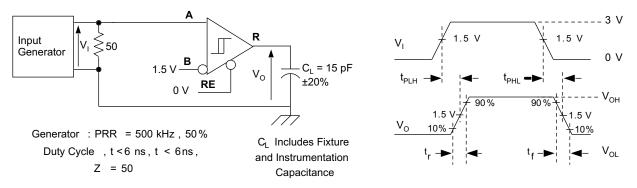


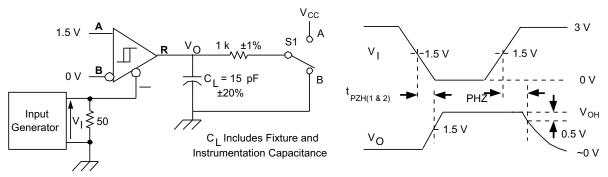
Figure 8. Receiver Voltage and Current Definitions

SLLS666-SEPTEMBER 2005



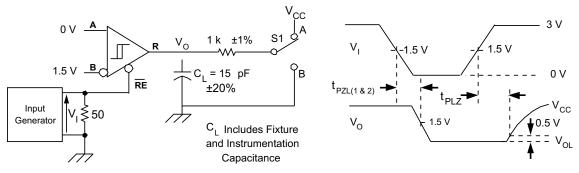
TEXAS ISTRUMENTS www.ti.com





Generator:  $P_{RR}$  = 500 kHz, 50%, Duty Cycle,  $t_r$  < 6 ns,  $t_f$  < 6 ns,  $Z_0$  = 50

#### Figure 10. Receiver High-Level Enable and Disable Time Test Circuit and Voltage Waveforms



Generator:  $P_{RR}$  = 500 kHz, 50%, Duty Cycle,  $t_r$  < 6 ns,  $t_f$  < 6 ns,  $Z_0$  = 50

#### Figure 11. Receiver Low-Level Enable and Disable Time Test Circuit and Voltage Waveforms

SLLS666-SEPTEMBER 2005

#### PARAMETER MEASUREMENT INFORMATION (continued)

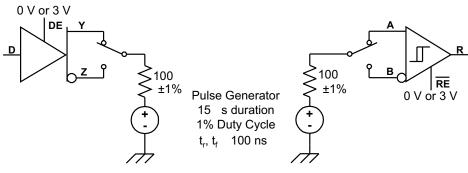


Figure 12. Test Circuit, Transient Overvoltage Test

### **DEVICE INFORMATION**

### LOW-POWER SHUTDOWN MODE

When both the driver and receiver are disabled (DE low and RE high) the device is in shutdown mode. If the enable inputs are in this state for less than 60 ns, the device does not enter shutdown mode. This guards against inadvertently entering shutdown mode during driver/receiver enabling. Only when the enable inputs are held in this state for 300 ns or more, the device is assured to be in shutdown mode. In this low-power shutdown mode, most internal circuitry is powered down, and the supply current is typically less than 1 nA. When either the driver or the receiver is re-enabled, the internal circuitry becomes active.

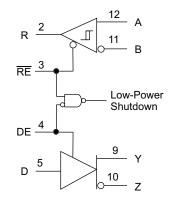


Figure 13. Low-Power Shutdown Logic Diagram

If only the driver is re-enabled (DE transitions to high) the driver outputs are driven according to the D input after the enable times given by  $t_{PZH2}$  and  $t_{PZL2}$  in the driver switching characteristics. If the D input is open when the driver is enabled, the driver outputs defaults to A high and B low, in accordance with the driver failsafe feature.

If only the receiver is re-enabled ( $\overline{RE}$  transitions to low) the receiver output is driven according to the state of the bus inputs (A and B) after the enable times given by  $t_{PZH2}$  and  $t_{PZL2}$  in the receiver switching characteristics. If there is no valid state on the bus the receiver responds as described in the failsafe operation section.

If both the receiver and driver are re-enabled simultaneously, the receiver output is driven according to the state of the bus inputs (A and B) and the driver output is driven according to the D input. Note that the state of the active driver affects the inputs to the receiver. Therefore, the receiver outputs are valid as soon as the driver outputs are valid.

**DEVICE INFORMATION (continued)** 

SLLS666-SEPTEMBER 2005

**FUNCTION TABLES** 



## SN65HVD53, SN65HVD54, SN65HVD55, SN65HVD58, SN65HVD59 DRIVER

11	IPUTS	OUT	PUTS
D	DE	Y	Z
Н	Н	Н	L
L	Н	L	Н
Х	L or open	Z	Z
Open	Н	L	Н

#### SN65HVD53, SN65HVD54, SN65HVD55, SN65HVD58, SN65HVD59 RECEIVER

DIFFERENTIAL INPUTS $V_{ID} = V_A - V_B$	ENABLE RE	OUTPUT R
$V_{ID} \leq -0.2 V$	L	L
$-0.2 \text{ V} < \text{V}_{\text{ID}} < -0.02 \text{ V}$	L	?
$-0.02 \text{ V} \leq \text{V}_{\text{ID}}$	L	Н
Х	H or open	Z
Open Circuit	L	Н
Idle circuit	L	Н
Short Circuit, $V_A = V_B$	L	Н

#### SN65HVD50, SN65HVD51, SN65HVD52, SN65HVD56, SN65HVD57 DRIVER

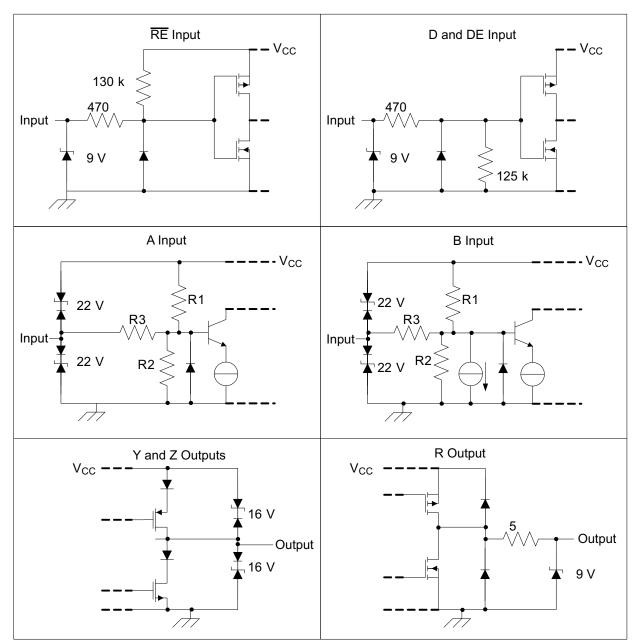
	OUTPUTS				
INPUT D	Y	Z			
Н	Н	L			
L	L	Н			
Open	L	Н			

#### SN65HVD50, SN65HVD51, SN65HVD52, SN65HVD56, SN65HVD57 RECEIVER

DIFFERENTIAL INPUTS $V_{ID} = V_A - V_B$	OUTPUT R
$V_{ID} \leq -0.2 V$	L
$-0.2 \text{ V} < \text{V}_{\text{ID}} < -0.02 \text{ V}$	?
$-0.02 \text{ V} \leq \text{V}_{\text{ID}}$	Н
Open Circuit	Н
Idle circuit	Н
Short Circuit, V <sub>A</sub> = V <sub>B</sub>	Н

SLLS666-SEPTEMBER 2005





	R1/R2	R3
SN65HVD50, SN65HVD53, SN65HVD56, SN65HVD58	9 kΩ	45 kΩ
SN65HVD51, SN65HVD52, SN65HVD54, SN65HVD55 SN65HVD57, SN65HVD58, SN65HVD59	36 kΩ	180 kΩ



#### **TYPICAL CHARACTERISTICS**

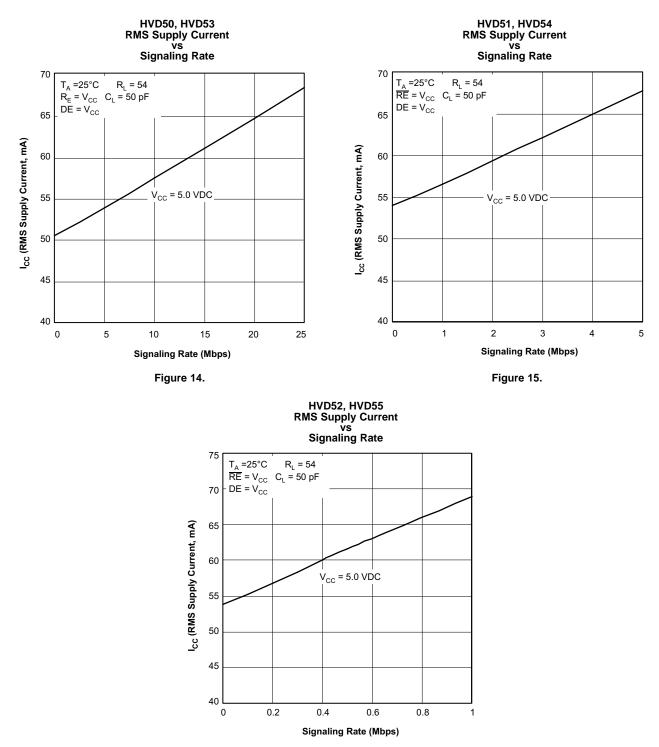


Figure 16.

## **TYPICAL CHARACTERISTICS (continued)**

ij

INS

Texas

0.12

0.1

0.08

0.06

0.04

0.02

0

0

1

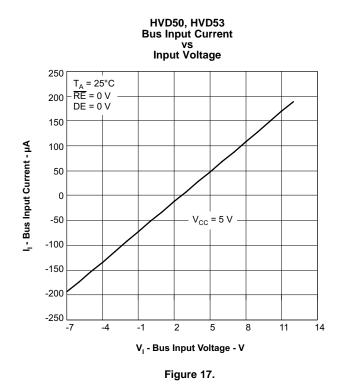
-0.02

IoL - Low-level Output Current - A

VCC = 5 V

DE = V<sub>CC</sub> D = 0 V

TRUMENTS www.ti.com



Driver Low-Level Output Current vs Low-Level Output Voltage

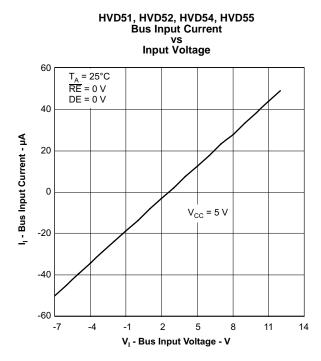
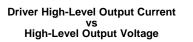
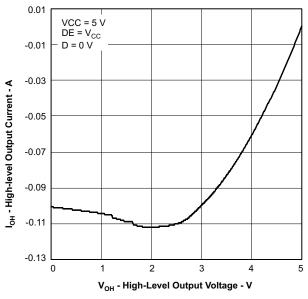


Figure 18.







V<sub>OL</sub> - Low-Level Output Voltage - V

2

3

4

5

Figure 20.

SLLS666-SEPTEMBER 2005

## **TYPICAL CHARACTERISTICS (continued)**

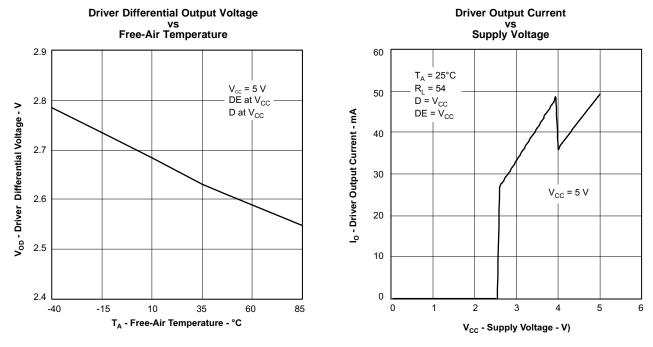


Figure 21.

Figure 22.



## **APPLICATION INFORMATION**

### THERMAL CHARACTERISTICS OF IC PACKAGES

 $\theta_{JA}$  (Junction-to-Ambient Thermal Resistance) is defined as the difference in junction temperature to ambient temperature divided by the operating power.

 $\theta_{JA}$  is not a constant and is a strong function of:

- the PCB design (50% variation)
- altitude (20% variation)
- device power (5% variation)

 $\theta_{JA}$  can be used to compare the thermal performance of packages if the specific test conditions are defined and used. Standardized testing includes specification of PCB construction, test chamber volume, sensor locations, and the thermal characteristics of holding fixtures.  $\theta_{JA}$  is often misused when it is used to calculate junction temperatures for other installations.

TI uses two test PCBs as defined by JEDEC specifications. The low-k board gives *average* in-use condition thermal performance, and it consists of a single copper trace layer 25 mm long and 2-oz thick. The high-k board gives best *case* in-use condition, and it consists of two 1-oz buried power planes with a single copper trace layer 25 mm long and 2-oz thick. A 4% to 50% difference in  $\theta_{IA}$  can be measured between these two test cards

 $\theta_{JC}$  (Junction-to-Case Thermal Resistance) is defined as difference in junction temperature to case divided by the operating power. It is measured by putting the mounted package up against a copper block cold plate to force heat to flow from die, through the mold compound into the copper block.

 $\theta_{JC}$  is a useful thermal characteristic when a heatsink applied to package. It is *not* a useful characteristic to predict junction temperature because it provides pessimistic numbers if the case temperature is measured in a nonstandard system and junction temperatures are backed out. It can be used with  $\theta_{JB}$  in 1-dimensional thermal simulation of a package system.

 $\theta_{JB}$  (Junction-to-Board Thermal Resistance) is defined as the difference in the junction temperature and the PCB temperature at the center of the package (closest to the die) when the PCB is clamped in a cold-plate structure.  $\theta_{JB}$  is only defined for the high-k test card.

 $\theta_{JB}$  provides an overall thermal resistance between the die and the PCB. It includes a bit of the PCB thermal resistance (especially for BGA's with thermal balls) and can be used for simple 1-dimensional network analysis of package system, see Figure 23.

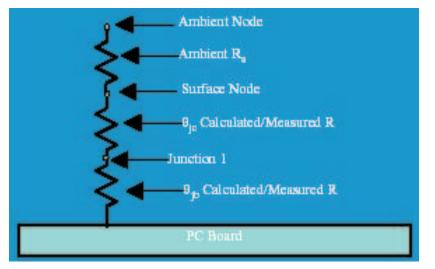


Figure 23. Thermal Resistance

### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN65HVD53D	PREVIEW	SOIC	D	14	50	TBD	Call TI	Call TI
SN65HVD53DR	PREVIEW	SOIC	D	14	2500	TBD	Call TI	Call TI
SN65HVD54D	PREVIEW	SOIC	D	14	50	TBD	Call TI	Call TI
SN65HVD54DR	PREVIEW	SOIC	D	14	2500	TBD	Call TI	Call TI
SN65HVD55D	PREVIEW	SOIC	D	14	50	TBD	Call TI	Call TI
SN65HVD55DR	PREVIEW	SOIC	D	14	2500	TBD	Call TI	Call TI

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN65HVD53D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD53DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD53DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD53DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD54D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD54DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD54DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD54DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD55D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD55DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD55DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD55DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

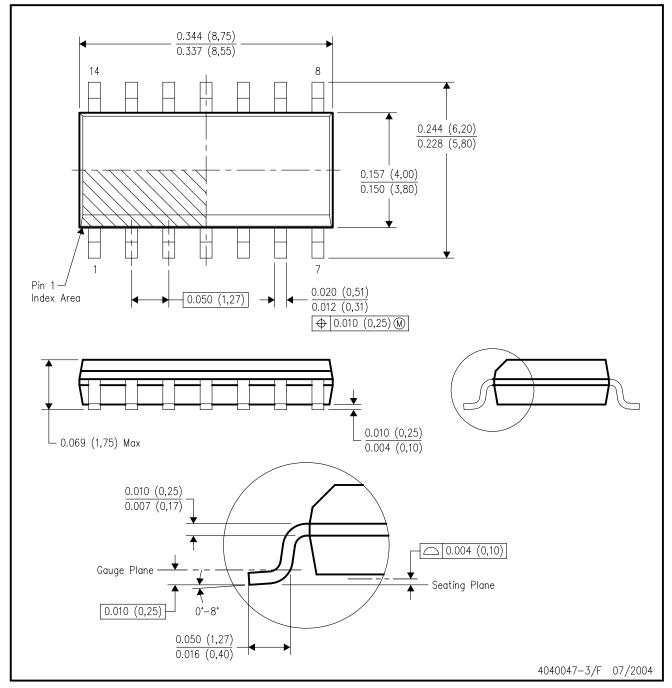
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012 variation AB.



#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address:

Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

Copyright © 2005, Texas Instruments Incorporated

Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com